

74HC7014

Hex non-inverting precision Schmitt-trigger

Rev. 3 — 30 April 2014

Product data sheet

1. General description

The 74HC7014 is a hex buffer with precision Schmitt-trigger inputs. The precisely defined trigger levels are lying in a window between $0.55 \times V_{CC}$ and $0.65 \times V_{CC}$. It makes the circuit suitable to operate in a highly noisy environment. Input shorts are allowed to -1.5 V and $+16$ V without disturbing other channels. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} . Schmitt trigger inputs transform slowly changing input signals into sharply defined jitter-free output signals.

2. Features and benefits

- Operating voltage 3.0 V to 6.0 V
- Complies with JEDEC standard no. 7A
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ◆ MM JESD22-A115A exceeds 200 V
- Multiple package options
- Specified from -40 °C to $+85$ °C and from -40 °C to $+125$ °C

3. Applications

- Wave and pulse shapers for highly noisy environments

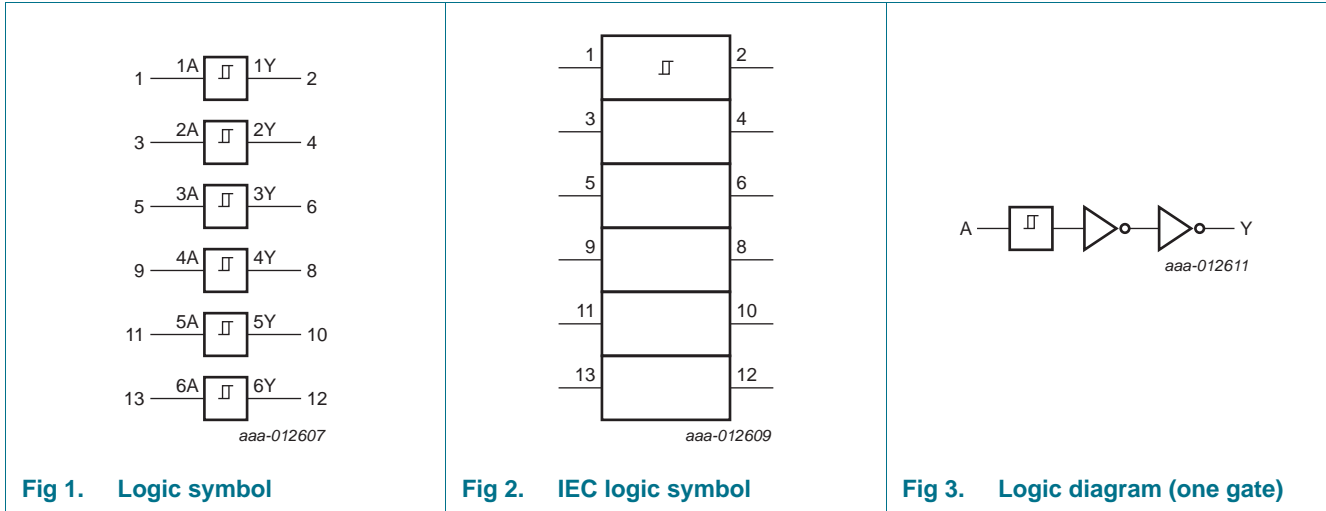
4. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC7014N	-40 °C to $+125$ °C	DIP14	plastic dual in-line package; 14 leads (300 mil)	SOT27-1
74HC7014D	-40 °C to $+125$ °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1

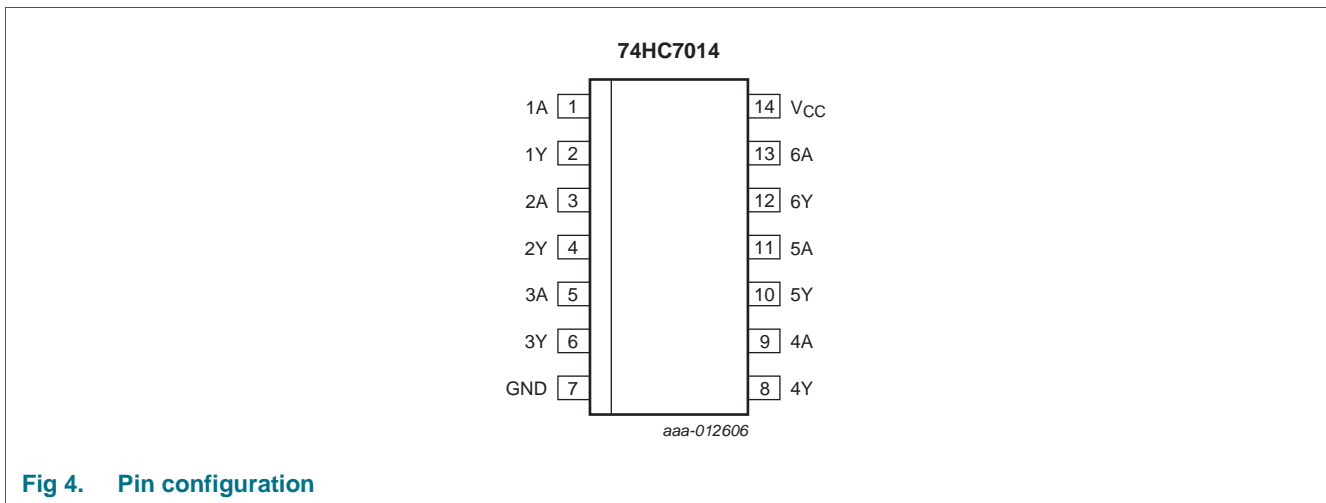


5. Functional diagram



6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1A to 6A	1, 3, 5, 9, 11, 13	data input
1Y to 6Y	2, 4, 6, 8, 10, 12	data output
GND	7	ground (0 V)
V _{CC}	14	supply voltage

7. Functional description

Table 3. Functional table^[1]

Input	Output
nA	nY
L	L
H	H

[1] H = HIGH voltage level; L = LOW voltage level

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7	V
I_{IK}	input clamping current	$V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$ ^[1]	-	±20	mA
I_{OK}	output clamping current	$V_O < -0.5\text{ V}$ or $V_O > V_{CC} + 0.5\text{ V}$ ^[1]	-	±20	mA
I_O	output current	$-0.5\text{ V} < V_O < V_{CC} + 0.5\text{ V}$	-	25	mA
I_{CC}	supply current		-	50	mA
I_{GND}	ground current		-50	-	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	total power dissipation	DIP14 ^[2]	-	750	mW
		SO14 ^[2]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For DIP14 package: P_{tot} derates linearly with 8 mW/K above 70 °C.
For SO14 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage		2.0	5.0	6.0	V
V_I	input voltage		0	-	V_{CC}	V
V_O	output voltage		0	-	V_{CC}	V
T_{amb}	ambient temperature		-40	-	+125	°C

10. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	T _{amb} = 25 °C			T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}								
		I _O = -20 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I _O = -5.2 mA; V _{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}								
		I _O = 20 μA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
I _I	input leakage current	V _{CC} = 6.00 V; V _I = V _{CC} or GND	-	-	0.1	1.0	-	1.0	-	μA
		V _{CC} = 3.00 V to 6.00 V; V _I = 16 V or GND	-	-	0.5	5.0	-	5.0	-	μA
I _{CC}	DC supply current	V _{CC} = 3.00 V	-	0.7	1.4	-	1.8	-	2.1	mA
		V _{CC} = 5.25 V	-	3.0	6.0	-	7.5	-	7.5	mA
		V _{CC} = 6.00 V	-	3.7	7.4	-	10.0	-	13.0	mA
C _I	input capacitance		-	3.5	-	-	-	-	-	pF

11. Dynamic characteristics

Table 7. Dynamic characteristics

$GND = 0\text{ V}$; for test circuit, see [Figure 6](#).

Symbol	Parameter	Conditions	$T_{\text{amb}} = 25\text{ °C}$			$T_{\text{amb}} = -40\text{ °C to }+125\text{ °C}$		Unit
			Min	Typ	Max	Max (85 °C)	Max (125 °C)	
t_{PHL}	HIGH to LOW propagation delay	nA to nY; see Figure 5						
		$V_{\text{CC}} = 3.00\text{ V}$	-	95	475		715	ns
		$V_{\text{CC}} = 4.75\text{ V}$	-	38	115	-	175	ns
		$V_{\text{CC}} = 6.00\text{ V}$	-	27	73	93	112	ns
t_{PLH}	LOW to HIGH propagation delay	nA to nY; see Figure 5						
		$V_{\text{CC}} = 3.00\text{ V}$	-	47	175	220	260	ns
		$V_{\text{CC}} = 4.75\text{ V}$	-	23	52	65	78	ns
		$V_{\text{CC}} = 6.00\text{ V}$	-	18	46	58	70	ns
t_t	transition time	see Figure 5 [1]						
		$V_{\text{CC}} = 3.00\text{ V}$	-	12	20	25	30	ns
		$V_{\text{CC}} = 4.75\text{ V}$	-	7	15	19	22	ns
		$V_{\text{CC}} = 6.00\text{ V}$	-	6	13	16	19	ns
C_{PD}	power dissipation capacitance	per gate; $V_I = GND$ to V_{CC} [2]	-	9	-	-	-	pF

[1] t_t is the same as t_{THL} and t_{TLH} .

[2] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{\text{PD}} \times V_{\text{CC}}^2 \times f_i \times N + \Sigma(C_L \times V_{\text{CC}}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

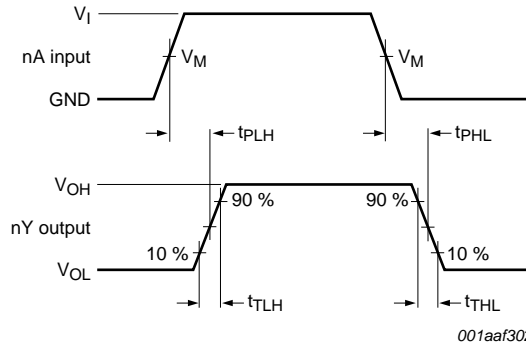
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

$\Sigma(C_L \times V_{\text{CC}}^2 \times f_o)$ = sum of outputs.

12. Waveforms

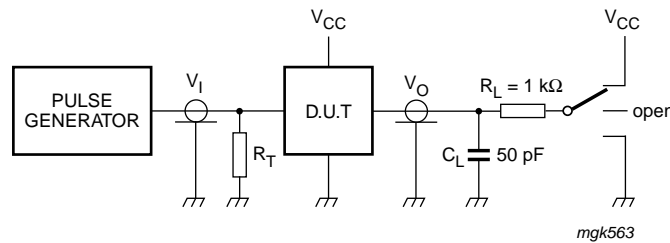


Measurement points are given in [Table 8](#).
 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 5. The input (nA) to output (nY) propagation delays and output transition times

Table 8. Measurement points

Type	Input	Output
	V_M	V_M
74HC7014	$0.5V_{CC}$	$0.5V_{CC}$



Test data is given in [Table 9](#).
 Definitions test circuit:
 R_L = Load resistance.
 C_L = Load capacitance including jig and probe capacitance.
 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

Fig 6. Test circuit for measuring switching times

Table 9. Test data

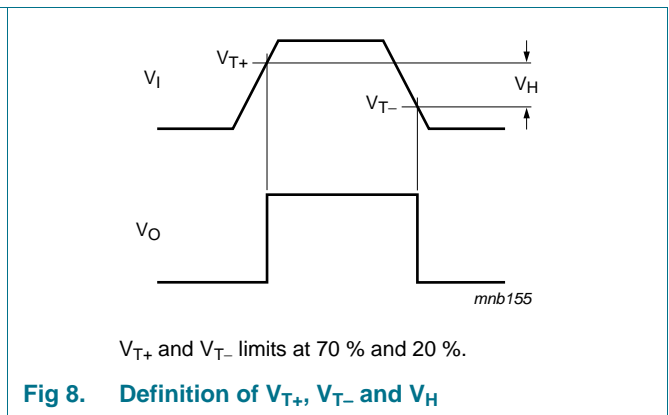
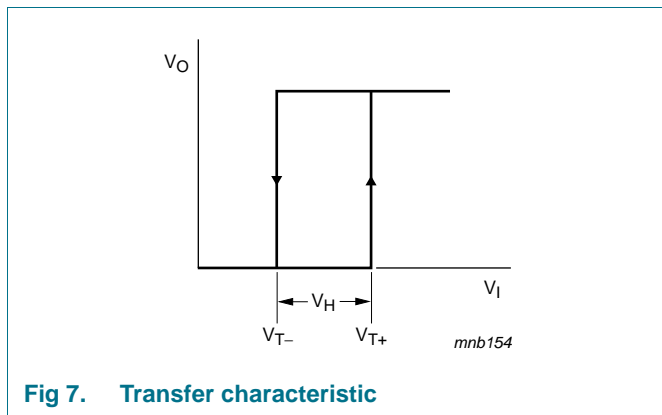
Type	Input	t_r, t_f	Test
	V_I		t_{PLH}, t_{PLH}
74HC7014	GND to V_{CC}	6 ns	open

13. Transfer characteristics

Table 10. Transfer characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); see [Figure 7](#) and [Figure 8](#).

Symbol	Parameter	Conditions	T _{amb} = 25 °C			T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
V _{T+}	positive-going threshold voltage	V _{CC} = 3.00 V	-	1.86	1.95	-	1.95	-	1.95	V
		V _{CC} = 4.75 V	-	2.94	3.08	-	3.08	-	3.08	V
		V _{CC} = 5.00 V	-	3.10	3.25	-	3.25	-	3.25	V
		V _{CC} = 5.25 V	-	3.25	3.41	-	3.41	-	3.41	V
		V _{CC} = 6.00 V	-	3.72	3.90	-	3.90	-	3.90	V
V _{T-}	negative-going threshold voltage	V _{CC} = 3.00 V	1.65	1.74	-	1.65	-	1.65	-	V
		V _{CC} = 4.75 V	2.62	2.76	-	2.62	-	2.62	-	V
		V _{CC} = 5.00 V	2.75	2.90	-	2.75	-	2.75	-	V
		V _{CC} = 5.25 V	2.89	3.05	-	2.89	-	2.89	-	V
		V _{CC} = 6.00 V	3.30	3.48	-	3.30	-	3.30	-	V
V _H	hysteresis voltage	V _{CC} = 3.00 V	50	120	-	50	-	50	-	V
		V _{CC} = 4.75 V	100	180	-	100	-	100	-	V
		V _{CC} = 5.00 V	120	200	-	120	-	120	-	V
		V _{CC} = 5.25 V	130	210	-	130	-	130	-	V
		V _{CC} = 6.00 V	160	240	-	160	-	160	-	V



14. Package outline

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1

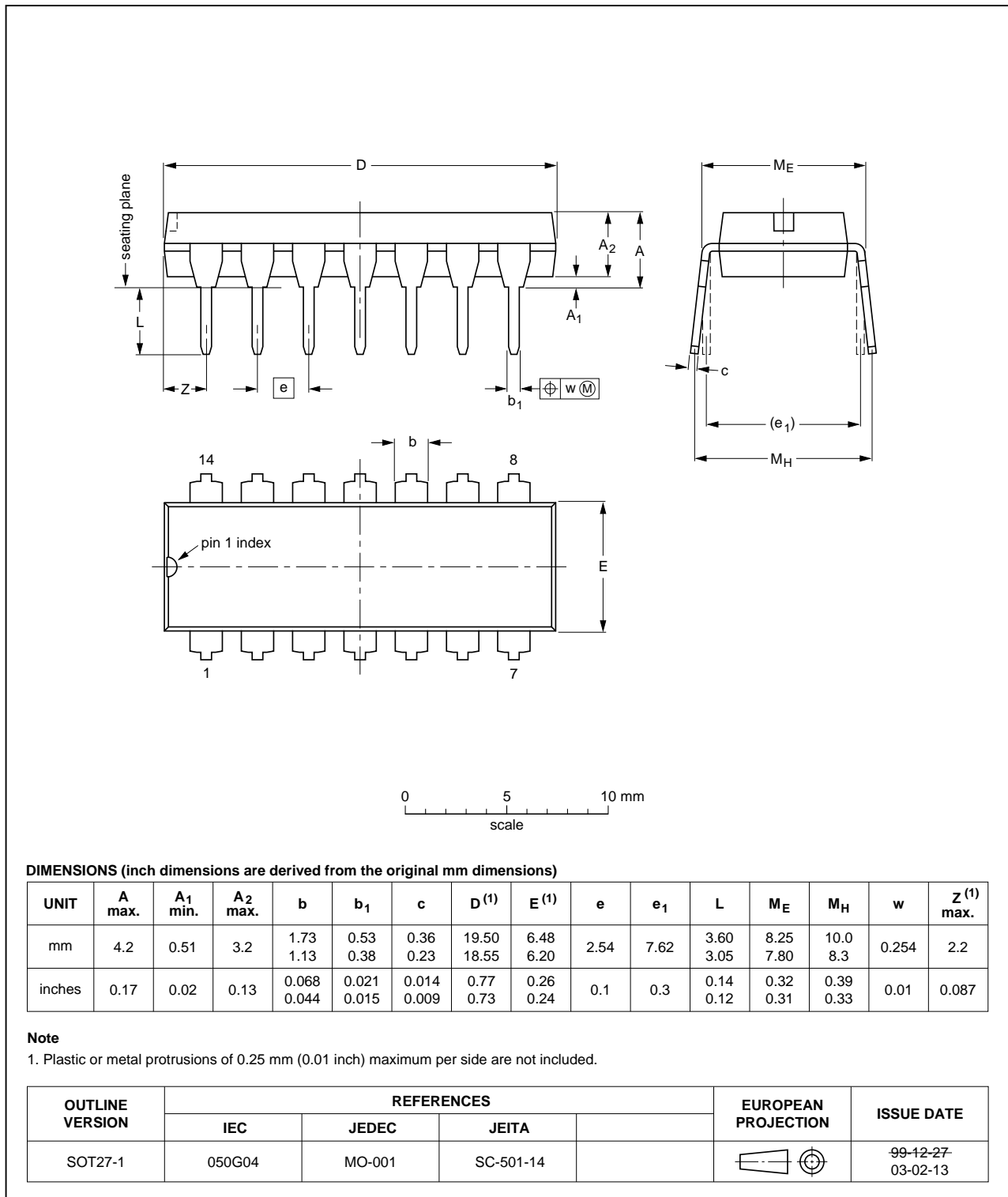


Fig 9. Package outline SOT27-1 (DIP14)

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1

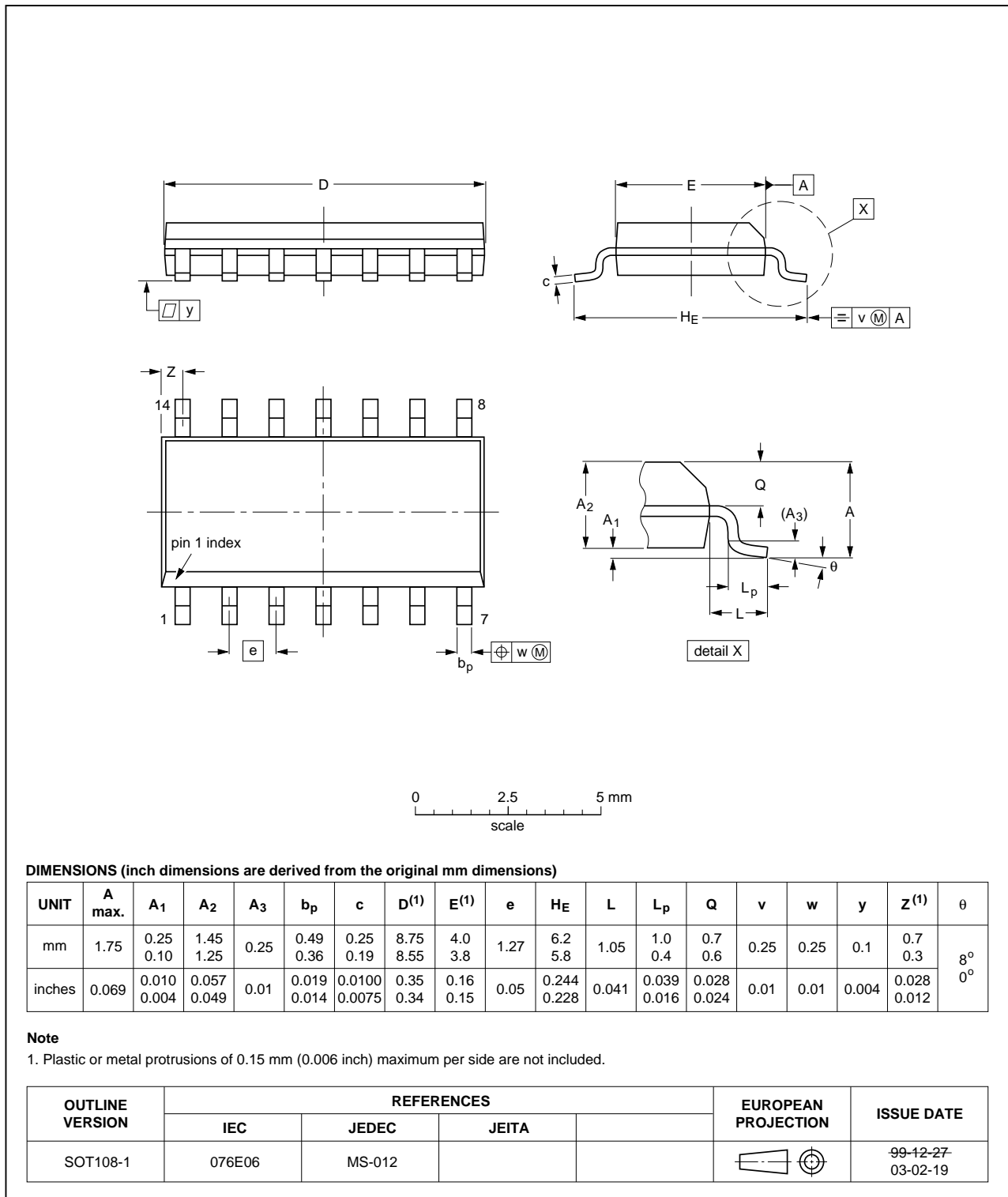


Fig 10. Package outline SOT108-1 (SO14)

15. Abbreviations

Table 11. Abbreviations

Acronym	Description
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

16. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC7014 v.3	20140430	Product data sheet	-	74HC7014_CVN v.2
Modifications:	<ul style="list-style-type: none">The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.Legal texts have been adapted to the new company name where appropriate.			
74HC7014_CVN v.2	19980708	Product specification	-	74HC7014 v.1
74HC7014 v.1	19930901	Product specification	-	-

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Document status ^{[1][2]}	Product status ^[3]	Definition
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[2] The term 'short data sheet' is explained in section "Definitions".

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